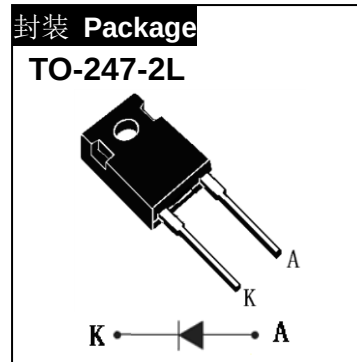




FP60F120AA

主要参数 MAIN CHARACTERISTICS

$I_F(AV)$	60A
V_{RRM}	1200V
$V_F(typ)$	2.75V
$T_{rr}(typ)$	60ns



用途

- 吸收回路
- 开关电源
- UPS
- 高频开关器件并联二极管

APPLICATIONS

- Snubber diode
- Switch power supply
- UPS
- Antiparalle Diode for high frequency switching devices

产品特性

- 超快恢复时间
- 低恢复损耗
- 低正向压降
- 低漏电流

FEATURES

- Ultrafast Recovery Time
- Low Recovery Loss
- Low Forward Voltage
- Low Leakage Current

订货信息 ORDER MESSAGE

订 货 型 号 Order codes		印 记 Marking	封 装 Package
有卤-条管 Halogen-Tube	无卤-条管 Halogen Free-Tube		
FP60F120AA-GL-B	FP60F120AA-GL-BR	FP60F120AA	TO-247-2L



绝对最大额定值 ABSOLUTE RATINGS ($T_c=25^{\circ}\text{C}$)

项 目 Parameter	符 号 Symbol	数 值 Value	单 位 Unit
反向重复峰值电压 Peak Repetitive Reverse Voltage	V_{RRM}	1200	V
平均正向整流电流 $T_c=100^{\circ}\text{C}$ Average Forward Rectified Current	$I_{F(AV)}$	60	A
非重复浪涌正向电流 Non-Repetitive Surge Forward Current $t=8.3\text{ms}$	I_{FSM}	550	A
结温 Junction Temperature	T_j	$-55\sim+175$	$^{\circ}\text{C}$
存储温度 Storage temperature range	T_{STG}	$-55\sim+150$	$^{\circ}\text{C}$

电特性 ELECTRICAL CHARACTERISTICS ($T_c=25^{\circ}\text{C}$ unless otherwise specified)

项 目 Parameter	测试条件 Tests conditions		最小值 Value(min)	典型值 Value(typ)	最大值 Value(max)	单位 Unit
V _R	I _R =50μA		1200	-	-	V
I _R	T _j =25℃	V _R =V _{RRM}	-	-	50	μA
	T _j =150℃		-	-	500	μA
V _F	T _j =25℃	I _F =60A	-	2.75	3.50	V
	T _j =150℃		-	2.05	2.80	V
trr	I _F =0.5A, I _R =1A, I _{RR} =0.25A		-	60	75	ns
trr	I _F =1A, V _R =30V, di _F /dt=-200A/μs		-	40	50	ns
trr	I _F =60A, V _R =200V, di _F /dt=-200A/μs T _c =25℃		-	50	-	ns
Q _{rr}			-	150	-	nc
I _{RRM}			-	5	-	A
trr	I _F =60A, V _R =200V, di _F /dt=-200A/μs T _c =150℃		-	160	-	ns
Q _{rr}			-	900	-	nc
I _{RRM}			-	15	-	A

热特性 THERMAL CHARACTERISTICS (maximum)

项 目 Parameter	符 号 Symbol	最大值 Value(max)	单 位 Unit
结到管壳的热阻 Thermal Resistance Junction to Case	$R_{th(j-c)}$	0.4	$^{\circ}\text{C}/\text{W}$



特征曲线 ELECTRICAL CHARACTERISTICS (curves)

Fig.1 Typical Forward Characteristics

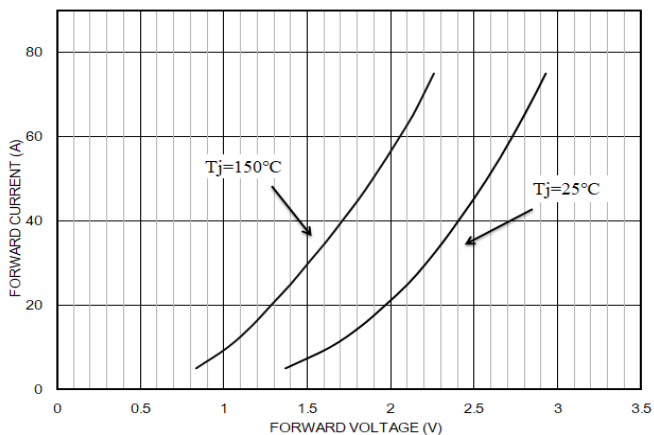


Fig.2 Typical Reverse Characteristics

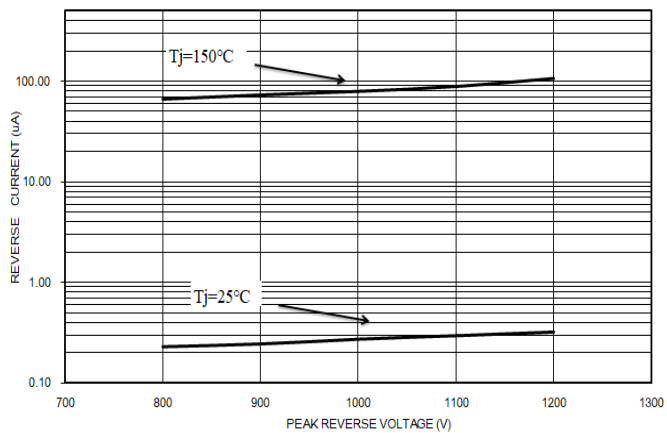
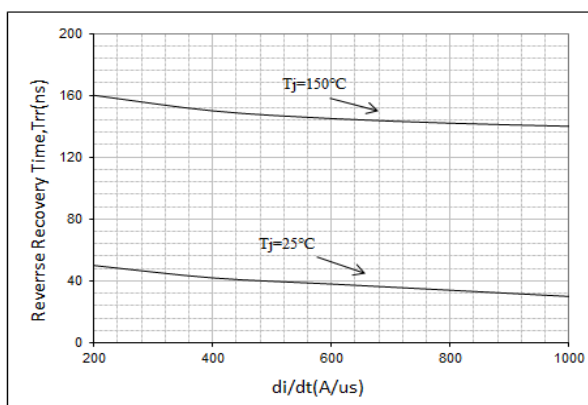
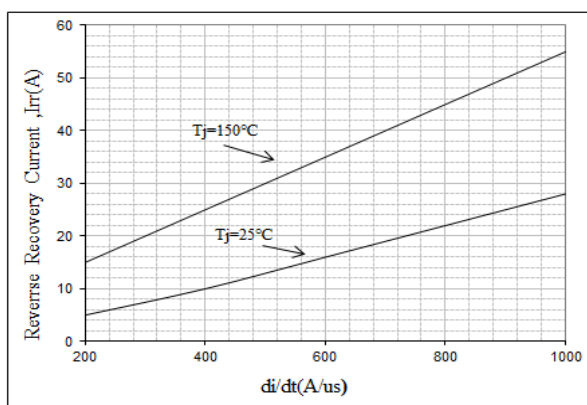
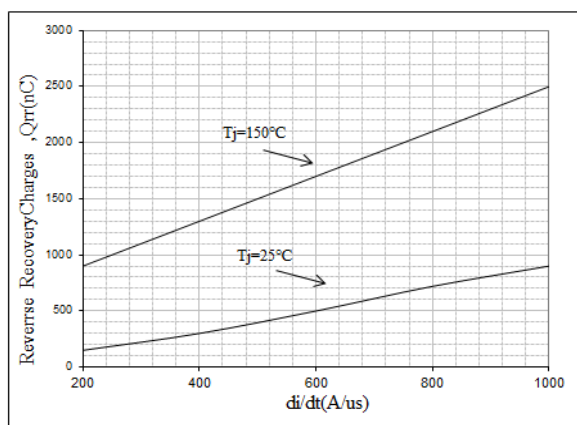
Fig.3 Reverse Recovery Time vs dI_F/dt Fig.4 Reverse Recovery Current vs dI_F/dt Fig.5 Reverse Recovery Charge vs dI_F/dt 

Fig.6 .Forward current vs Case temperature

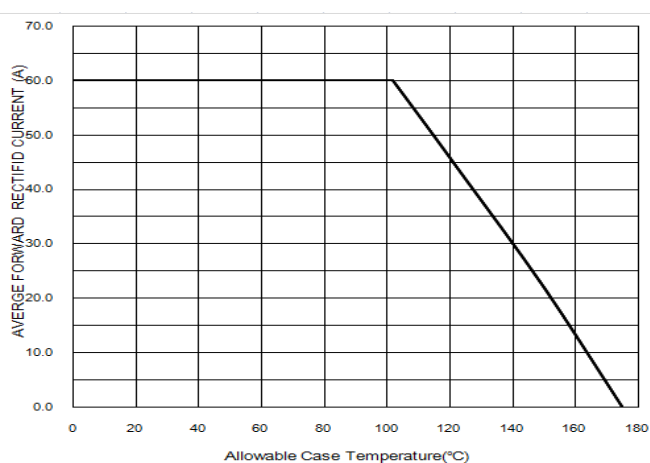
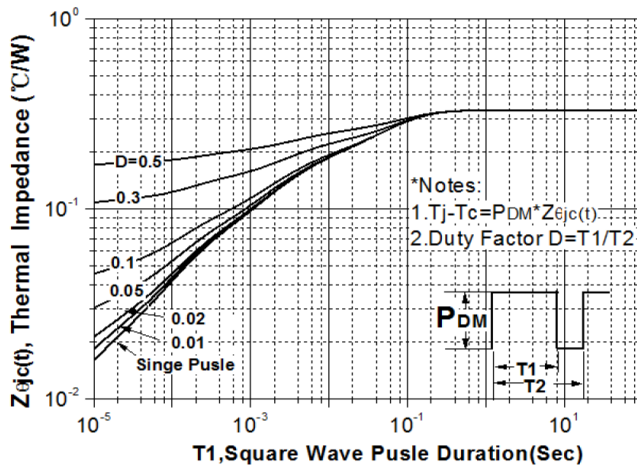


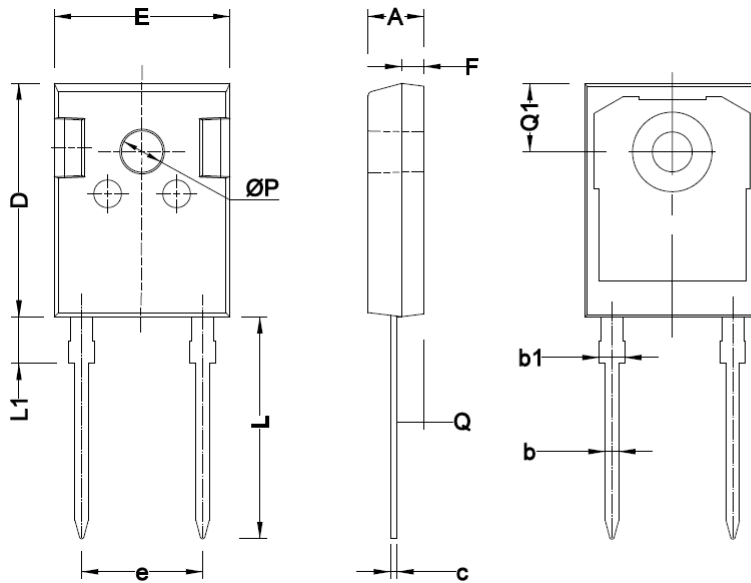
Fig.7 Transient Thermal Response Curve



外形尺寸 PACKAGE MECHANICAL DATA

TO-247- 2L

单位 Unit : mm



SYMBOL	MM	
	MIN	MAX
A	4.80	5.20
b	1.10	1.30
b1	1.95	2.25
c	0.50	0.70
D	20.80	21.20
E	15.60	16.00
F	1.85	2.15
e	10.73	11.03
L	19.62	20.22
L1	3.93	4.33
ΦP	3.40	3.80
Q	2.26	2.56
Q1	6.00	6.40



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3. 在电路设计时请不要超过器件的绝对最大额定值，否则会影响整机的可靠性。
4. 本说明书如有版本变更不另外告知。

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3. Please do not exceed the absolute maximum ratings of the device when circuit designing.
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